Applications of model-based transparent surface films analysis using coherence-scanning interferometry

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Abstract. Surface metrology must increasingly contend with submicron films, whose prevalence now extends to products well beyond semiconductor devices. For optical technologies such as coherence-scanning interferometry (CSI), transparent submicron films pose a dual challenge: film effects can distort the measured top surface topography map and metrology requirements may now include three-dimensional maps of film thickness. Yet CSI’s sensitivity also presents an opportunity: modeling film effects can extract surface and thickness information encoded in the distorted signal. Early model-based approaches entailed practical trade-offs between throughput and field of view and restricted the choice of objective magnification. However, more recent advances allow full-field surface films analysis using any objective, with sample-agnostic calibration and throughput comparable to film-free measurements. Beyond transparent films, model-based CSI provides correct topography for any combination of dissimilar materials with known visible-spectrum refractive indices. Results demonstrate single-nm self-consistency between topography and thickness maps. © The Authors. Published by SPIE under a Creative Commons Attribution 3.0 Unported License. Distribution or reproduction of this work in whole or in part requires full attribution of the original publication, including its DOI. [DOI: 10.1117/1.OE.56.11.111709]

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1 Introduction

1.1 Surface Metrology with Submicron Films

Surface metrology must increasingly contend with submicron films, whose prevalence now extends to products well beyond semiconductor devices. These films may be incidental, such as oil on a machined part, or of little direct concern to a user interested only in the top surface. Alternately, the film may be critical, protecting the underlying substrate or providing specific optical characteristics.

In any case, adding a submicron film to a component rarely relaxes previous surface metrology requirements. Instead these will generally expand to include film properties, such as thickness, uniformity, and texture.

1.2 Requirements for Surface Films Analysis

Ideally, a surface metrology technology adapted to measure submicron films will retain its performance for topography alone. This includes metrics, such as resolution and throughput, but also extends to configuration flexibility. For microscope-based technologies, this means that films analysis should not restrict the choice of objective or zoom.

As for the films metrology itself, associated calibrations should be sample-agnostic—a sample-specific calibration artifact (for example, matching bare substrate) may be costly or impractical. Measurements should exploit the available optical resolution: surface metrology previously producing high-resolution height maps should do likewise for thickness. Finally, surface films analysis should provide unambiguous results over a wide thickness search range. The user may have little knowledge of the thickness or thickness may vary widely over the measurement area.

1.3 Challenge and Opportunity for Coherence-Scanning Interferometry

Coherence-scanning interferometry (CSI) provides noncontact areal topography maps with sub-nm precision over a variety of surface types, including patterned semiconductor wafers, flat panel display components, automotive machined metal parts, transparent film structures, and MEMS devices. CSI determines surface topography from the localized coherence signal produced by interference between reflections from the sample and a reference surface. A typical CSI signal for a bare surface (i.e., no film) is shown in Fig. 1(a): surface location essentially corresponds to the peak envelope position.

A transparent film will generally produce an additional signal from the substrate. For thick films [Fig. 1(b)], the signals are well separated and can be easily assigned to the top surface and substrate. However, for sub-micron films the surface and substrate signals merge [Fig. 1(c)] and are no longer separable. But this sensitivity to films also presents an opportunity: if film effects can be modeled, the distorted CSI signal can be decoded to simultaneously determine surface and thickness.

2 Model-Based CSI

2.1 Overview

Model-based CSI simulates signals over an expected range of film properties and selects the best match with the measured signal. It has been presented in various forms, all using frequency-domain analysis to combine models for the system and of the part being measured. Thus a caveat with
model-based CSI is that film properties must be at least partly known to bound the search space and avoid degenerate solutions. In practice, this usually requires known visible-spectrum refractive indices for both substrate and film, with film thickness left as the unknown parameter to be determined. The film index is usually assumed to be constant, neglecting for example thickness dependence from quantum size effects that can emerge with ultra-thin films. Therefore, model-based CSI is typically most applicable for films that are thicker than about 50 nm.

### 2.2 Previous Approaches

A CSI signal can be represented as a function of spatial frequency $K$ over a range determined by the source wavelengths $\lambda$ in conjunction with the incident angles $\alpha$ supported by the system [with maximum $\alpha$ generally corresponding to the numerical aperture (NA) of the objective]. The wavelength and incident angle can be expressed in terms of angular wavenumber $k$ and directional cosine $\beta$

$$k = \frac{2\pi}{\lambda},$$

$$\beta = \cos(\alpha).$$

A given spatial frequency $K$ will then have contributions from any pairs of $k$ and $\beta$ satisfying

$$K = 2\beta k.$$  \hspace{1cm} (3)

This suggests modeling the response of the system and the part as a function of $k$ and $\beta$. This is shown in Fig. 2, where a ray bundle for a particular $(k, \beta)$ pair passes through a Mirau objective and reflects from the part. As previously presented in detail,\(^9\) contributing $(k, \beta)$ pairs can be summed incoherently for each spatial frequency $K$, which is discretized using a conventional fast Fourier transform or equivalent.

Modeling the complex reflectivity $z(k, \beta)$ of the part is straightforward\(^{14}\) if refractive indices for the substrate and film are known. For the system, some approaches to model-based CSI approximate incident angle as a single value averaged over the NA.\(^{11,15}\) This simplifies computation to a one-dimensional integration over $k$ and allows a straightforward field calibration using a conventional imaging tube-lens in the intended measurement configuration. However, such approaches are limited to lower NA systems.

The precursor to the approach presented here supports systems with any NA\(^{16,17}\) using a system model derived from the objective pupil that captures dependence on both $k$ and $\beta$, as shown in Fig. 2. Signal libraries are then generated over the expected range of film configurations, as shown in Fig. 3. However, performing the requisite pupil calibration requires a specialized Bertrand tube-lens. Also, with earlier approaches, the intensive computation entailed practical throughput trade-offs, typically limiting analysis to small subregions within the field of view.

### 2.3 Presented Approach

The approach presented here is similar in principle to its predecessor\(^{16}\) but separates calibration into two parts. Pupil calibration uses a nominal model, thereby avoiding any need for specialized hardware. Field calibration is performed in the desired measurement configuration to capture tool-specific characteristics. The procedure is compatible with a wide range of NA systems.
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3 Example Measurements

A modern commercial CSI microscope19 was used to measure a variety of parts with submicron films and dissimilar materials. For each measurement configuration, calibration was performed using only a silicon carbide flat, which is also used for standard-CSI calibrations.

3.1 Films Applications Requiring a Wide Search Range

All model-based approaches have some degree of degeneracy that can produce multiple solutions to the same set of model parameters. For films metrology, the outcome can be ambiguous or incorrect film thickness values that nonetheless yield apparently acceptable matching signals to the experimental data. One solution is to strictly limit the thickness search range; but this may be precluded by incomplete knowledge or by large variations in thickness over the measurement area. A more attractive approach taken here is to identify small but distinctive signal details that allow the removal of potential degenerate solutions and enable a wide search range.

Figure 5(a) shows a silicon substrate coated with silicon oxide with center thickness ∼1.2 μm. The outer rim of this coating exhibits a thickness gradient down to zero (bare silicon), where the substrate was masked by the fixture during evaporation. This transition region was measured using a 20x Mirau objective, using an oxide-on-silicon model with a search range of 0 to 1300 nm, and independent processing for all pixels in the field of view.

The resulting thickness map and a cross-sectional slice spanning the full thickness range are shown in Figs. 5(b) and 5(c). The thickness variation is continuous and monotonic as expected, indicating that the thickness was determined unambiguously throughout the wide search range. The silicon substrate, derived by subtracting thickness from the top surface, is flat as expected to within ∼1 nm.

3.2 Films Metrology over a Wide Range of Magnification

CSI’s large choice of magnifications enables a wide range of surface metrology applications, from measuring form to inspecting microscopic defects. This flexibility remains just as desirable with the addition of thin films, and indeed should extend to the metrology of the film itself. Ideally, model-based CSI should work over the full selection of optical configurations.

Figure 6 shows thickness maps measured for an oxide-on-silicon film standard (NIST certified thickness of 96.6 ± 0.4 nm) using four different objective/zoom combinations spanning a 70x range in magnification. For all cases, analysis used an oxide-on-silicon model with a search range of 0 to 1200 nm for all pixels in the field of view. The wide search range is deliberate, to verify robustness and emulate the case of film thickness being unknown.

The wide range of magnifications provides a thorough picture of film characteristics. The 1.4x Zygo wide field (ZWF) objective20 captures the entire certified region in a single field of view, revealing slow variations in film thickness. The concentric rings correspond to deliberate patterning in the film, with black rings indicating where the oxide is etched down to the silicon substrate. Measurements at higher magnifications reveal smaller-scale thickness variations, along with surface scratches resulting from handling of this laboratory sample. The highest-magnification map, obtained with a 50x Mirau, reveals details of individual striation defects.

In conjunction with the thickness maps shown in Fig. 6, model-based CSI also provides surface maps. Subtracting film thickness from the top surface yields a derived map of the substrate surface; collectively, these maps enable additional metrology and validation. Again, the range of magnifications enables a thorough surface analysis.

Results from the 1.4x ZWF capture regions of both oxide film and exposed silicon substrate, as shown in Fig. 7. The surface map reveals steps between the oxide and bare silicon. From the manufacturing sequence (blanket thermal oxidation followed by patterned etch down to silicon substrate), we expect that surface steps should match film thickness, or equivalently, that the underlying silicon substrate should be continuous. The substrate map confirms this, validating the overall measurement.

Measurements at higher magnification reveal textural differences between the surface, thickness, and substrate.
Figure 8 shows interface maps obtained from the 20× Mirau, with form (fourth-order polynomial) removed. The top surface exhibits both orange-peel texture and striations. Meanwhile, the film texture is dominated by striations whereas the substrate exhibits orange-peel texture but is free from striations. Collectively these maps reveal that the substrate contributes the orange-peel texture and that the striations reside in the top surface of the film (likely from usage, not an original defect).

3.3 Parts with Dissimilar Materials

Even bulk materials can confound conventional CSI if there are variations in phase-change on reflection (PCOR), as will occur between dissimilar materials. For example, a conventional CSI measurement of a glass/metal step will typically be biased by ~10 to 20 nm, with the metal appearing lower than in reality. More generally, a part can comprise both films and bulk dissimilar materials. Figure 9 shows the fabrication sequence for such a sample, in the form of trench oxide-on-silicon with a partial gold overcoat. First, ~1 μm of thermal silicon oxide was grown on a silicon substrate. Next trenches were formed in the oxide via photoresist masking and a partial etch, deliberately leaving thinner oxide at the trench bottom. Finally, trenches were partially gold-coated by a lift-off sequence (photoresist masking, global gold deposition, and photoresist strip). Target gold thickness was ~90 nm, sufficient to essentially eliminate film effects from the underlying oxide.

This sample was measured using a 50× Mirau objective, with analysis tailored to each region: for the uncoated oxide, an oxide-on-silicon model with a search range of 0 to 1200 nm; and for the gold overcoat, a bulk-gold model (i.e., no film). Figure 10 shows surface and thickness maps for a pair of trenches over a gold-coating boundary.
The thickness of the unetched oxide was measured to be 988 nm. For the trenches, thickness depends slightly on their width: 160 nm for the 20-μm trench and 165 nm for the 10-μm trench. By subtraction, thickness results suggest trench depths of 828 and 823 nm for the 20- and 10-μm trenches, respectively.

This is corroborated by the results of Fig. 11, which shows cross-sectional surface-map profiles through both trenches, and on both sides of the coating boundary, i.e., with and without gold overcoat. The 10-μm trench is ∼5 nm shallower than the wider 20-μm trench, and is consistent with its oxide thickness measuring as 5 nm thicker, as in Fig. 10(b). Moreover, measured trench depths agree with thickness-suggested results to better than 1 nm. Overall, surface and thickness results reveal that the oxide-etch process was about 0.6% slower in the narrower 10-μm trench. As further corroboration, trench-depth measurements on either side of the coating boundary—obtained using completely independent analyses, with and without film effects—agree to better than 1 nm. This self-consistency extends earlier work demonstrating nm-level agreement between trench depths measured with model-based CSI and an atomic force microscope.

Some applications require correct topography across dissimilar regions. For this sample, this corresponds to the gold-thickness step across the coating boundary. Figure 12 shows gold-thickness profiles measured over dissimilar oxide film thicknesses: 160 nm within the 20-μm trench and 988 nm in adjacent unetched oxide. Both profiles indicate a gold thickness of about 85 nm with agreement to ∼1 nm.

### 4 Summary

The presented approach to model-based CSI enables full-field films surface metrology over a full range of interferometric objective magnification, producing high-resolution maps of surface and film thickness. Calibration is sample-agnostic, and for most practical search ranges, measurement time is comparable to that of conventional CSI. Beyond transparent films, model-based CSI provides PCOR-corrected topography for any combination of dissimilar materials with known visible-spectrum refractive indices, including metals.

Results demonstrate single-nm self-consistency between topography and thickness maps, provided refractive indices are well known. This represents an important caveat with model-based CSI: poor knowledge of material properties will limit performance and may even prevent a meaningful measurement. A natural next step for model-based CSI would be to extend capabilities to tolerate uncertainty in material properties.
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